# International Rectifier

# MBR2535CT MBR2545CT

#### SCHOTTKY RECTIFIER

30 Amp

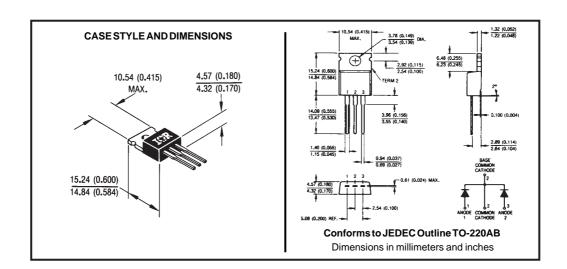
#### **Major Ratings and Characteristics**

Characteristics	MBR25CT	Units
I <sub>F(AV)</sub> Rectangular waveform	30	А
V <sub>RRM</sub>	35/45	V
I <sub>FSM</sub> @ tp=5µssine	1060	А
V <sub>F</sub> @30 Apk, T <sub>J</sub> = 125°C	0.73	V
T <sub>J</sub>	-65 to 150	°C

#### **Description/Features**

The MBR25..CT center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150° C T operation
- Center tap TO-220 package
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



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# MBR2535CT, MBR2545CT

PD-2.322 rev. A 12/97

# Voltage Ratings

	Part number	MBR2535CT	MBR2545CT	
V <sub>R</sub>	Max. DC Reverse Voltage (V)	05	45	
V <sub>RWN</sub>	Max. Working Peak Reverse Voltage (V)	35	45	

# Absolute Maximum Ratings

	Parameters	MBR25CT	Units	Conditions	
I <sub>F(AV)</sub>	Max.AverageForwardCurrent	30	Α	@T <sub>C</sub> =130°C,(RatedV <sub>R</sub> )	
I <sub>FSM</sub>	Max. Peak One Cycle Non Repetitive Surge	1060	А	5μs Sine or 3μs Rect. pulse Following any rated load condition and with rated V <sub>RRM</sub> applied	
		150		Surgeappliedatratedloadconditionhalfwavesingle phase60Hz	
I <sub>RRM</sub>	PeakRepetitiveReverseSurgeCurrent	1.0	Α	2.0 µsec 1.0 KHz	

#### **Electrical Specifications**

Electrical epochications					
	Parameters	MBR25CT	Units	C	Conditions
V <sub>FM</sub>	Max. Forward Voltage Drop	0.82	V	@ 30A	T <sub>J</sub> = 25 °C
	(1)	0.73	V	@ 30A	T <sub>J</sub> = 125 °C
I <sub>RM</sub>	Max. Instantaneus Reverse Current	0.2	mA	$T_J = 25 ^{\circ}\text{C}$	Rated DC voltage
	(1)	40	mA	T <sub>J</sub> = 125 °C	Rated DC voltage
C <sub>T</sub>	Max. Junction Capacitance	900	рF	$V_R = 5V_{DC}$ , (test signal range 100Khz to 1Mhz) 25°C	
L <sub>s</sub>	Typical Series Inductance	8.0	nΗ	Measured from top of terminal to mounting plane	
dv/dt		1000	V/ µs		

<sup>(1)</sup> Pulse Width < 300µs, Duty Cycle <2%

# Thermal-Mechanical Specifications

	Parameters		MBR25CT	Units	Conditions
T <sub>J</sub>	Max.JunctionTemperatureR	ange	-65to 150	°C	
T <sub>stg</sub>	Max.StorageTemperatureR	ange	-65to175	℃	
R <sub>thJC</sub>	Max.ThermalResistanceJultoCase	nction	1.50	°C/W	DCoperation
R <sub>thCS</sub>	TypicalThermalResistance, toHeatsink	Case	0.50	°C/W	Mountingsurface, smooth and greased
wt	ApproximateWeight		2(0.07)	g(oz.)	
Т	MountingTorque	Min.	6(5)	Kg-cm	
		Max.	12(10)	(lbf-in)	
	Case Style		TO-220A	.B	JEDEC

<sup>\*</sup> For Additional Informations and Graphs, Please See the 30CTQ Series

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